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r:O Drafts			
Hit		DRs	Time Stame
1 1	*10/256805*	US-PGPUB;	2004/07/27
2 0	"10/669780" "60/505533" "60/505880" "10/671303" "10/701183"	US-PGPUB;	2004/07/27
3 18	("5192580" "5288528" "5347144" "5523192" "5563019" "5625199" "5766819" "5840463" "5981970" "6051318" "6143451"	USPAT	2004/07/27
4 1	(*20020149315*).pn.	US-PGPUB;	2004/07/27
	9257/40,642,E39.007,E51.001,E51.003,E51.01,E51.011,E51.013,E51.015,E51.017,E51.024,E51.027,E27.117,E25.008.ccls.	US-PGPUB;	2004/07/27
5 412		US-PGPUB;	2004/07/27
7 449	(257/40,642,E39.007,E51.001,E51.003,E51.01,E51.011,E51.013,E51.015,E51.017,E51.024,E51.027,E27.117,E25.008.ccls.	US-PGPUB;	2005/01/18
8 62	(257/40,642,E39.007,E51.001,E51.003,E51.01,E51.011,E51.013,E51.015,E51.017,E51.024,E51.027,E27.117,E25.008.ccls.	US-PGPUB;	2004/07/27
9 3538	pi-electrons" or (pi adj electrons)	US-PGPUB;	2004/07/27
10 5	("pi-electrons" or (pi adj electrons)) and	US-PGPUB;	2004/07/27
11 4065	(sulfur adj bond) or (silicon adj bond)	US-PGPUB;	2004/07/27
12 0	((sulfur adj bond) or (silicon adj bond)) and	US-PGPUB;	2004/07/27
13 3	((sulfur ad) bond) or (silicon ad) bond)) and	US-PGPUB;	2004/07/27
14 19	(*5192580****5288528****55347144*****5523192***5563019****5625199***5766619****5940463*****5981970****76051318*****6143451*******	US-PGPUB;	2005/01/18
15 530	(257/40,642,E39.007,E51.001,E51.003,E51.01,E51.011,E51.013,E51.015,E51.017,E51.024,E51.027,E27.117,E25.000.ccls.	US-PGPUB;	2005/01/18
16 1144	j.430,40000306306	US-PGPUB;	2005/01/18
17 135	315 and 316	US-PGPUB;	2005/01/18
18 62	S15 and S16 and aromatic	US-PGPUB;	2005/01/18
19 55	S15 and S16 and aromatic and transistor	US-PGPUB;	2005/01/19
20 50	S15 and S16 and aromatic and transistor and source and drain and gate	US-PGPUB;	2005/01/18
21 43	S15 and S16 and aromatic and transistor and source and drain and gate and dielectric	US-PGPUB;	2005/01/19
22 0	"y conjugated pi-electrons".clm.	US-PGPUB;	2005/01/19
23 0	*10/722613*	US-PGPUB;	2005/01/19
24 0	"wherein m is 1 and said alkyl groups are placed at symmetric positions on said anthracene".clm.	US-PGPUB;	2005/01/19
25 0	(wherein adj m adj 322 adj said adj alkyl adj groups adj placed adj symmetric adj positions adj said adj	US-PGPUB;	2005/01/19
26 2323	archine and via mine	US-PGPUB;	2005/01/19
27 2	(positions and symmetric and alkyl and anthracene).clm.	US-PGPUB;	2005/01/19
28 51	(organic adj semiconductor and conjugated).clm.	US-PGPUB;	2005/01/19
29 4	(organic adj semiconductor and conjugated and sulfur).clm.	US-PGPUB;	2005/01/19
30 530		US-PGPUB;	2005/01/19
100000000000000000000000000000000000000	#400/00 00 205 205 3001- #407/5051- #20/000 001 220 1 000 11- #400/410 #421- #400/4 11 0021- #20/001-	US-PGPUB;	2005/01/19
32 6	S30 and S31 and aromatic and transistor and source and drain and gate and dielectric and thiol	US-PGPUB;	2005/01/19
33 0	(organic adj semiconductor) same non-aromatic	US-PGPUB;	2005/01/19
34 0	(organic adj semiconductor) same (non adj aromatic)	US-PGPUB;	2005/01/19
35 4	(organic adi semiconductor) same (nonaromatic)	US-PGPUB;	2005/01/19
1			
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